

Si photodiode S2281 series

Si photodiode with BNC connector



S2281 series is Si photodiodes sealed in a metal package with a BNC connector. This configuration allows easy connection to Hamamatsu C2719 photosensor amplifier (S2281-01 has a large terminal capacitance which may cause a gain peaking to occur when C2719 is used with the gain set to the "M" range.). Two different spectral response characteristics are provided and the large active area makes S2281 series well suited for optical power meters. A variant type S9219 with a visual compensation filter is also available. Hamamatsu also provides E2573 BNC-BNC coaxial cable (length: 1 m) as an option.

Features

- Metal package with BNC connector
- High sensitivity
- High reliability

Applications

- Analytical instruments
- Optical measurement equipment

General ratings

Parameter	S2281	S2281-01	S2281-04	Unit
Active area size	φ11.3	φ11.3	φ7.98	mm
Active area	100	100	50	mm ²
Package	Metal package with BNC connector			-
Window material	Quartz glass			-

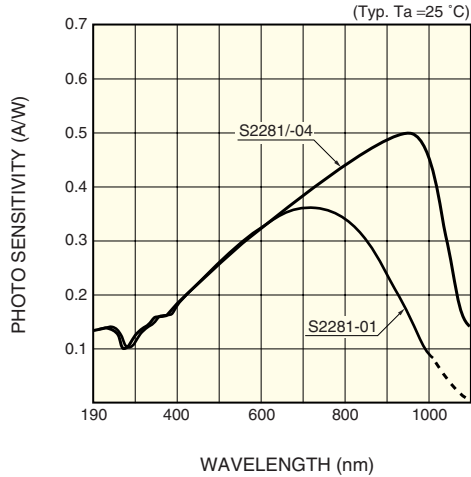
Absolute maximum ratings

Parameter	Symbol	S2281	S2281-01	S2281-04	Unit
Reverse voltage	V _R Max.	5			V
Operating temperature	T _{opr}	-10 to +60			°C
Storage temperature	T _{stg}	-20 to +70			°C

Electrical and optical characteristics (T_a=25 °C, unless otherwise noted)

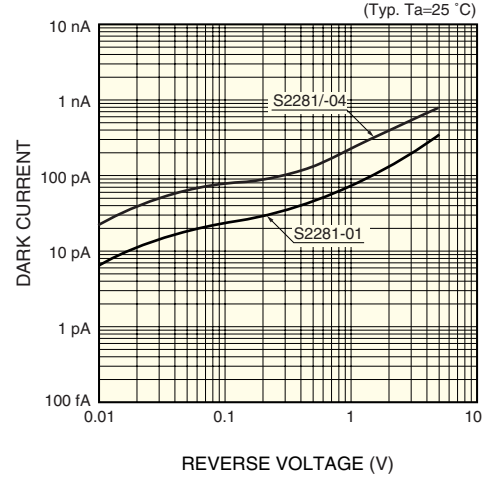
Parameter	Symbol	Condition	S2281			S2281-01			S2281-04			Unit
			Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
Spectral response range	λ		-	190 to 1100	-	-	190 to 1000	-	-	190 to 1100	-	nm
Peak sensitivity wavelength	λ _p		-	960	-	-	720	-	-	960	-	nm
Photo sensitivity	S	λ=200 nm	0.10	0.12	-	0.10	0.12	-	0.10	0.12	-	A/W
		λ=λ _p	-	0.5	-	-	0.36	-	-	0.5	-	
Short circuit current	I _{sc}	100 I _x	64	80	-	32	40	-	32	40	-	μA
Dark current	I _D	V _R =10 mV	-	50	500	-	6	300	-	50	500	pA
Shunt resistance	R _{sh}	V _R =10 mV	20	200	-	30	1700	-	20	200	-	MΩ
Rise time	t _r	V _R =0 V R _L =1 kΩ	-	3	-	-	7	-	-	3	-	μs
Terminal capacitance	C _t	V _R =0 V f=10 kHz	-	1300	-	-	3200	-	-	1300	-	pF
Noise equivalent power	NEP		-	2.0×10 ⁻¹⁴	-	-	8.6×10 ⁻¹⁵	-	-	1.8×10 ⁻¹⁴	-	W/Hz ^{1/2}

■ Spectral response



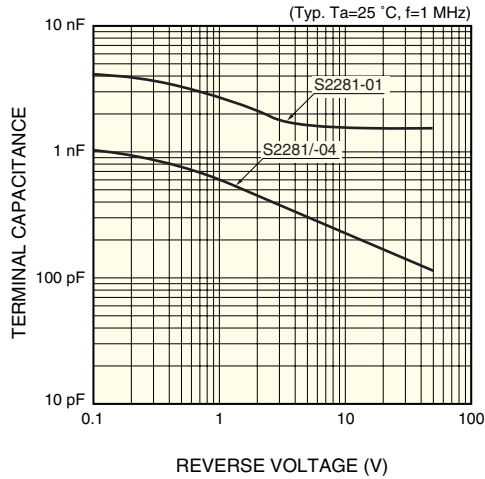
KSPDB0090EA

■ Dark current vs. reverse voltage



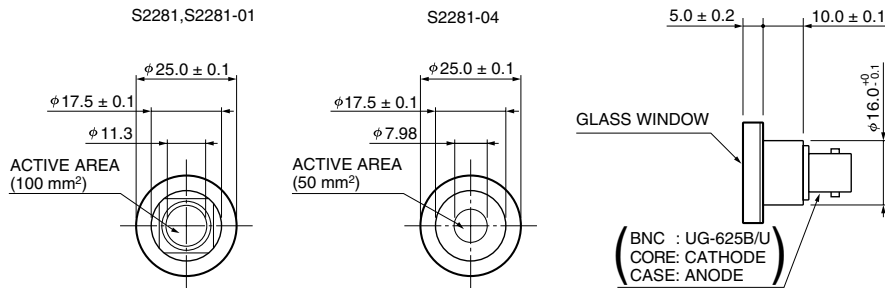
KSPDB0180EA

■ Terminal capacitance vs. reverse voltage



KSPDB0181EA

■ Dimensional outlines (unit: mm)



KSPDA0080EA

HAMAMATSU

HAMAMATSU PHOTONICS K.K., Solid State Division

1126-1 Ichino-cho, Hamamatsu City, 435-8558 Japan, Telephone: (81) 053-434-3311, Fax: (81) 053-434-5184, <http://www.hamamatsu.com>

U.S.A.: Hamamatsu Corporation, 360 Foothill Road, P.O. Box 6910, Bridgewater, N.J. 08807-0910, U.S.A., Telephone: (1) 908-231-0960, Fax: (1) 908-231-1218

Germany: Hamamatsu Photonics Deutschland GmbH, Arzbergerstr. 10, D-82211 Herrsching am Ammersee, Germany, Telephone: (49) 08152-3750, Fax: (49) 08152-2658

France: Hamamatsu Photonics France S.A.R.L.: 8, Rue du Saule Trappu, Parc du Moulin de Massy, 91882 Massy Cedex, France, Telephone: 33-(1) 69 53 71 00, Fax: 33-(1) 69 53 71 10

United Kingdom: Hamamatsu Photonics UK Limited, 2 Howard Court, 10 Tewin Road, Welwyn Garden City, Hertfordshire AL7 1BW, United Kingdom, Telephone: (44) 1707-294888, Fax: (44) 1707-325777

North Europe: Hamamatsu Photonics Norden AB, Smidesvägen 12, SE-171 41 Solna, Sweden, Telephone: (46) 8-509-031-00, Fax: (46) 8-509-031-01

Italy: Hamamatsu Photonics Italia S.R.L.: Strada della Moia, 1/E, 20020 Arese, (Milano), Italy, Telephone: (39) 02-935-81-733, Fax: (39) 02-935-81-741

Information furnished by HAMAMATSU is believed to be reliable. However, no responsibility is assumed for possible inaccuracies or omissions. Specifications are subject to change without notice. No patent rights are granted to any of the circuits described herein. ©2003 Hamamatsu Photonics K.K.